

1525 d. 2
09/496506

09/02/00

Class	Subclass	ISSUE CLASSIFICATION

U.S. UTILITY Patent Application

<i>NS</i> O.I.P.E.	PATENT DATE
SCANNED <i>BC</i> Q.A. <i>OP</i>	

APPLICATION NO. 09/496506	CONT/PRIOR D <i>CIP</i>	CLASS <i>284</i> <i>257</i>	SUBCLASS <i>27</i>	ART UNIT <i>2811</i>	EXAMINER <i>CRANE</i>
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APPLICANTS
TITLE

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9/426204
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Silicon Nanoparticle Field Effect Transistor And Transistor Memory Device

PTO-2040
12/99

ISSUING CLASSIFICATION									
ORIGINAL			CROSS REFERENCE(S)						
CLASS		SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)					
INTERNATIONAL CLASSIFICATION									

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				ISSUE FEE	
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<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____				ISSUE BATCH NUMBER	
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